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# COMPOUND FIELD EFFECT POWER TRANSISTOR $\mu$ PA 1576

## N-CHANNEL POWER MOS FET ARRAY SWITCHING TYPE

#### **DESCRIPTION**

The  $\mu$ PA1576 is N-channel Power MOS FET Array that built in 4 circuits designed for solenoid, motor and lamp driver.

#### **FEATURES**

- 4 V driving is possible
- Large Current and Low On-state Resistance

 $ID(pulse) = \pm 6 A$ 

 $RDS(on) \leq 1.2 \Omega MAX. (VGS = 10 V)$ 

RDS(on)  $\leq 1.5 \Omega$  MAX. (Vgs = 4 V)

• 2.54 mm Pitch (0.1 inch)

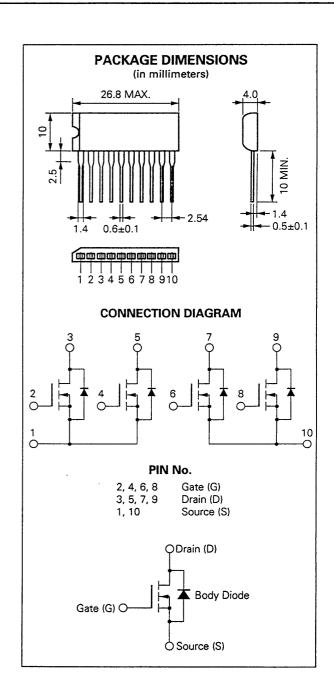
#### **ORDERING INFORMATION**

Part Number	Package	Quality Grade
μPA1576H	10 pin SIP	Standard

Please refer to "Quality grade on NEC Semiconductor Devices" (Document number IEI-1209) published by NEC Corporation to know the specification of quality grade on the devices and its recommended applications.

#### ABSOLUTE MAXIMUM RATINGS (Ta = 25 °C)

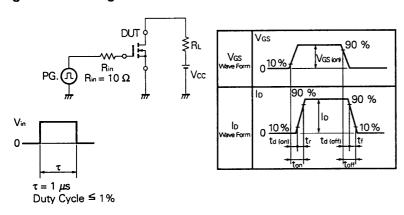
		,						
Drain to Source Voltage	Voss	100	V					
Gate to Source Voltage	Vgss	±20	V					
Drain Current (DC)	ID(DC)	±2.0	A/unit					
Drain Current (pulse)	D(pulse)	• ±6.0	A/unit					
Total Power Dissipation (4 cir	rcuits)							
<tc 25="" =="" °c=""></tc>	PT1	28	W					
Total Power Dissipation (4 circuits)								
<ta 25="" =="" °c=""></ta>	PT2	3.5	W					
Storage Temperature	Tstg	-55 to +150	°C					
Junction Temperature	Tj	150	°C					
* PW ≤ 300 μs, Duty Cycle ≤ 10 9	%							



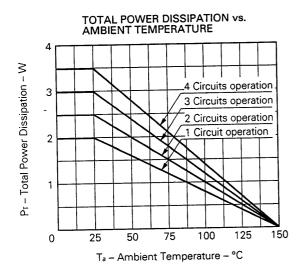
### **ELECTRICAL CHARACTERISTICS (Ta = 25 °C)**

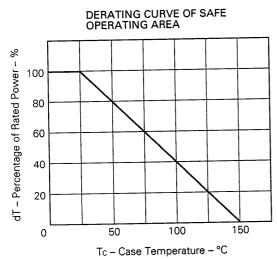
CHARACTERISTIC	SYMBOL	MIN.	TYP.	MAX.	UNIT	TEST CONDITIONS	
Drain Leakage Current	loss			10	μА	Vps = 100 V, Vgs = 0	
Gate to Source Leakage Current	lgss			±100	nA	$V_{GS} = \pm 20 \text{ V, } V_{DS} = 0$	
Gate to Source Cutoff Voltage	VGS(off)	1.0		2.5	٧	Vos = 10 V, lo = 1 mA	
Forward Transfer Admittance	yfs	0.5	1.6		S	Vos = 10 V, ID = 1 A	
Drain to Source On-state Resistance	RDS(on)1		0.8	1.2	Ω	Vgs = 10 V, lp = 1 A	
Drain to Source On-state Resistance	RDS(on)2		1.0	1.5	Ω	VGS = 4 V, iD = 1.0 A	
Input Capacitance	Ciss		200		рF	V <sub>DS</sub> = 10 V V <sub>GS</sub> = 0 f = 1.0 MHz	
Output Capacitance	Coss		70		pF		
Reverse Transfer Capacitance	Crss		15		pF		
Turn-On Delay Time	td(on)		45		ns	I <sub>D</sub> = 1 A V <sub>G</sub> S = 10 V V <sub>C</sub> C = 50 V R <sub>L</sub> = 50 $\Omega$ , R <sub>in</sub> = 10 $\Omega$ See Fig. 1	
Rise Time	tr		40		ns		
Turn-Off Delay Time	td(off)		450		ns		
Fall Time	tr		110		ns		

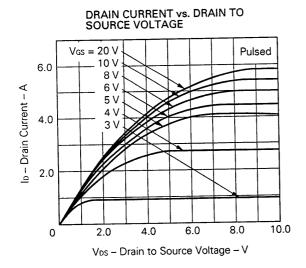
## Fig. 1 Switching Time Test Circuit

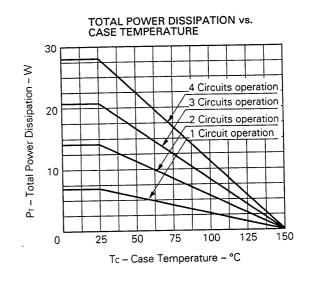


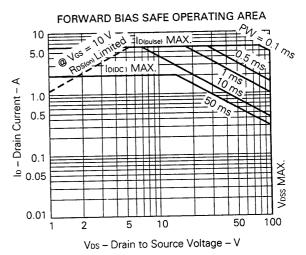
## TYPICAL CHARACTERISTICS (Ta = 25 °C)

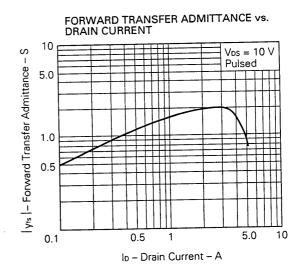


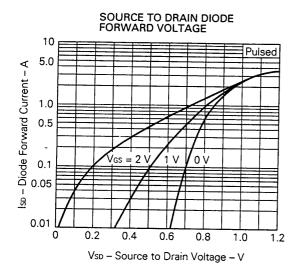


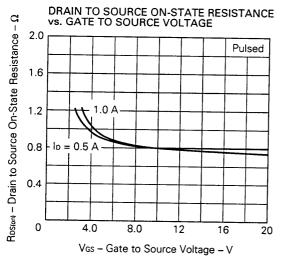


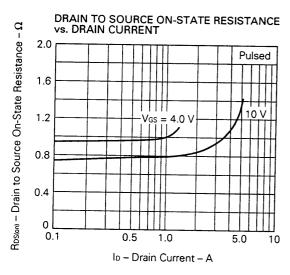


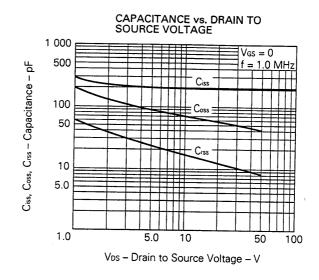


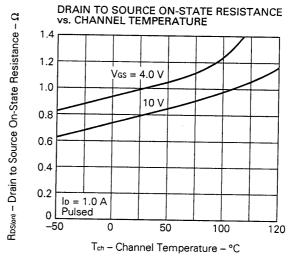


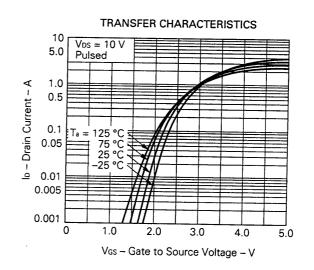


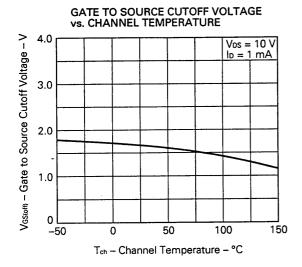


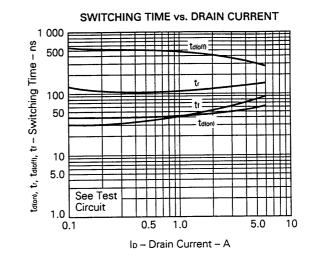












#### Reference

Document name	Document No. TEI-1202	
Quality control of NEC semiconductors devices.		
Quality control guide of semiconductors devices.	MEI-1202	
Assembly manual of semiconductors devices.	IEI-1207	
Safe operating area of Power MOS FET	TEA-1034	
Appication circuit using Power MOS FET	TEA-1035	

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